NSN 5961-01-208-6504

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-208-6504

Inclosure Material:

Metal

Overall Length:

1.573 inches

Overall Height:

Between 0.250 inches and 0.350 inches

Overall Width:

1.050 inches

Overall Diameter:

0.875 inches

End Application:

1430-01-092-1208 patriot

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

60.0 collector to base voltage/static/emitter open and 60.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

Between 15.00 amperes source cutoff current and 50.00 amperes source cutoff current

Power Rating Per Characteristic:

300.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Lug terminal bonded to base of transistor; junction pattern arrangement: npn

Test Data Document:

18876-11462589 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

2 uninsulated wire lead and 1 case

Shelf Life:

N/a

Unit Of Measure:

NSN 5961-01-208-6504

Transistor - Page 2 of 2

Demilitarization:

No

Fiig:

A110a0

